Vishay Semiconductors

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VS-20CTH03-M3

PRIMARY CHARACTERISTICS						
I _{F(AV)} 2 x 10 A						
V _R	300 V					
V _F at I _F	0.85 V					
t _{rr} typ.	See Recovery table					
T _J max.	175 °C					
Package	3L TO-220AB					
Circuit configuration	Common cathode					

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage		V _{RRM}		300	V			
Average rectified forward current	per diode	I	T _C = 160 °C	10				
Average rectilied forward current	per device	IF(AV)		20	А			
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C	120				
Operating junction and storage tempera	T _J , T _{Stg}		-65 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	300	-	-		
		I _F = 10 A	-	1.05	1.25	V	
Forward voltage	V _F	I _F = 10 A, T _J = 125 °C	-	0.85	0.95		
Povereo lockogo ourrent		$V_{R} = V_{R}$ rated	-	-	20		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	6	200	μA	
Junction capacitance	CT	V _R = 300 V	-	30	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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(Pb) RoHS



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DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
		I _F = 1 A, dI _F /dt = 50 A	õs, V _R = 30 V	-	-	35			
Reverse recovery time	+	I _F = 1 A, dI _F /dt = 100 A/µs, V _R = 30 V		-	-	30	ns		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	31	-	115		
		T _J = 125 °C		-	42	-			
Dook rooovon, ourront	1	T _J = 25 °C	I _F = 10 A dI _F /dt = 200 A/μs V _R = 200 V	-	2.4	-	А		
Peak recovery current	I _{RRM}	T _J = 125 °C		-	5.6	-	A		
	0	T _J = 25 °C		-	36	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	120	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS								
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, junction-to-case per diode	R _{thJC}	Mounting surface, flat, smooth, and greased	-	-	1.5	°C/W		
Marking device		Case style 3L TO-220AB	20CTH03					

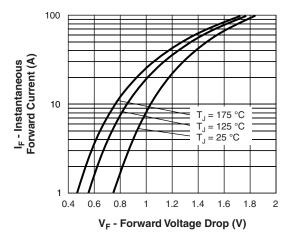


Fig. 1 - Typical Forward Voltage Drop Characteristics

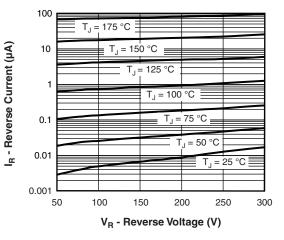


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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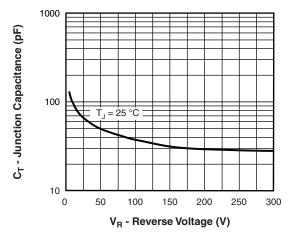


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

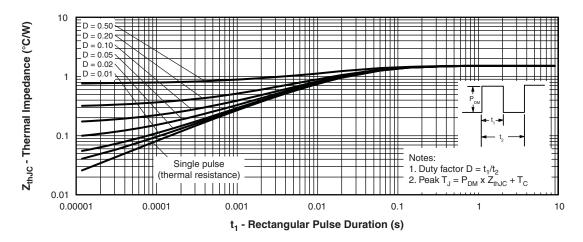
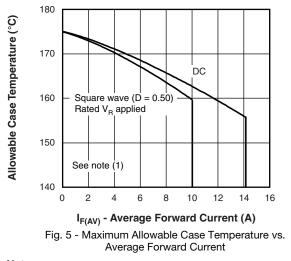
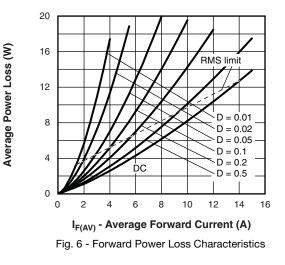


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ 5); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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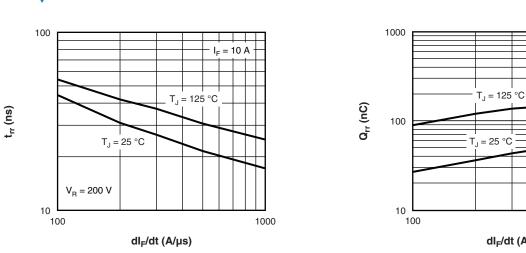


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

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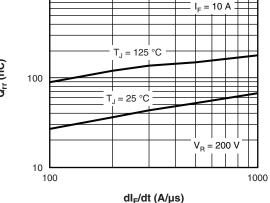


Fig. 8 - Typical Stored Charge vs. dl_F/dt

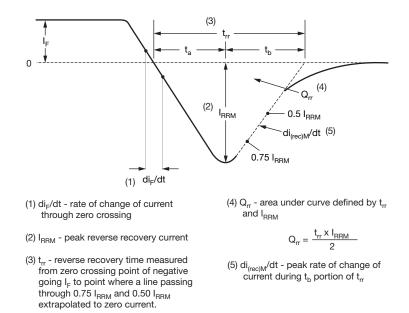


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

		1					
Device code	VS-	20	С	т	н	03	-M3
	1	2	3	4	5	6	7
	_						
	1	- Visł	nay Sem	iconduc	ctors pro	oduct	
	2	- Cur	rent rati	ng (20 =	20 A)		
	3	- C =	commo	on catho	de		
	4	- T=	TO-220	, D ² PAk	(TO-26	63AB)	
	5	- H=	hyperfa	st recov	/ery		
	6	- Volt	age rati	ng (03 =	: 300 V)		
	7	- Env	ironmer	ntal digit	:		
		-M3	s = halog	gen-free	, RoHS	-compli	ant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-20CTH03-M3	50	1000	Antistatic plastic tube				

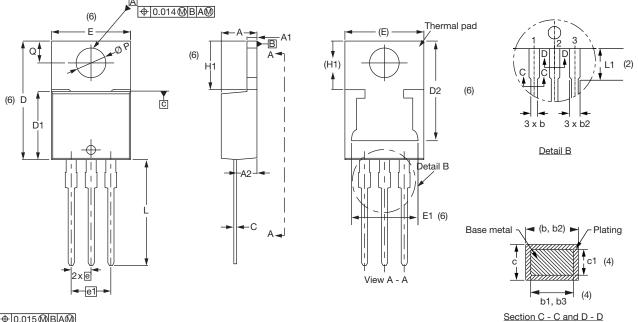
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96154			
Part marking information	www.vishay.com/doc?95028			
SPICE model	www.vishay.com/doc?96583			



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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	MILLIMETERS		INCHES		
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.50	2.92	0.098	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.35	0.585	0.604	3	
D1	8.38	9.02	0.330	0.355		

_		
Conforms to JEDEC [®]	outline	TO-220AB

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Ш	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

- ⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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